## NSN 5961-01-326-0621

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-326-0621 **Inclosure Material:** Glass **Overall Length:** Between 0.145 inches and 0.175 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.075 inches **End Application:** Joint tactical information distribution system (jtids); navstar global positioning system (control segment); navstar global positioning system user equipment (ue) **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.0 reverse breakdown voltage, dc and 15.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 microamperes forward current, average horsepower metric **Power Rating Per Characteristic:** 100.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 13499-353-3783 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No